**Introduction.** Graphene can pave new ways for the development of nanoscale photonic and optoelectronic devices [1]. Graphene plasmons [2–10] (GPs) are especially interesting due to their ultrastrong confinement, which may lead to a strong enhancement of the light-matter interaction [11–15]. Due to current limitations of the mobility of charge carriers in graphene samples, plasmon propagation lengths are not large compared to the free-space wavelength $\lambda$. However, they can still be large compared to the graphene plasmon wavelength $\lambda_p$, which can be as small as $\lambda/100$. For this reason, interesting resonant effects occur in graphene structures of deep subwavelength scales. For instance, resonant enhancement of absorption due to the excitation of GPs has recently been proposed [16–18] and demonstrated [19,20].

In particular, resonant plasmonic effects have been measured in arrays of ribbons in an ample range of ribbons widths [18,20–24]. Often, as is evident in these works, the analysis of the resonant absorption peaks has been based on the comparison with the dispersion relation of two-dimensional (2D) GPs via the relation $k = \pi / W$, where $W$ is the “active” part of the graphene ribbon (i.e., the region having a sufficiently high concentration of charge carriers). This simple relation between the modes inside the ribbon and 2D GPs corresponds to a Fabry-Pérot cavity with ideally reflecting walls and is justified by the high value of the GP reflection coefficient at a graphene edge [25,26]. Such an interpretation is, however, only valid when the phase shift of the GP reflected from the ribbon termination is $-\pi$.

In this Rapid Communication we show an influence of the phase picked up by a GP upon reflection at a graphene edge. We will demonstrate that this is a very important contribution, which affects both the resonator frequency and the nature of the electromagnetic (EM) modes.

**Phase picked up by reflection at an edge.** It is now well known that when a GP reaches an edge, it is reflected with

$$\Phi_{R} = \Phi_{10} - \Phi_{1} = \frac{\pi}{2} \approx -\frac{\pi}{2} \text{ or } \Phi_{R} = -\frac{\pi}{2}.$$
pattern with regions of zero field in the plane confirms that the scattered field is essentially a backreflected GP.

The different contributions to the magnetic field are represented in Fig. 2(a), clearly showing that, beyond a transition region at very small distances to the edge, the incident and reflected wave have the same period and virtually the same amplitude, but present a phase shift.

To characterize this phase shift we define the auxiliary function $\Phi_R(x)$ through the reflected field $H_r$:

$$H_r(x,z) = |H_r(x,z=0^+)|e^{-ik_px}e^{i\Phi_R(x)}.$$  \hspace{1cm} (1)

Defined in this way, $\Phi_R(x)$ is just a reparametrization of the phase of the reflected field but, at sufficiently long distances from the edge, it converges to the phase pickup by the GP upon the reflection at the edge, $\Phi_R \equiv \Phi_R(x \to -\infty)$. Figure 2(b) shows the computed $\Phi_R(x)$ for several wavelengths, both for free-standing graphene and for graphene on a silicon dioxide (SiO$_2$) substrate. Two regions are apparent in this figure. First, at small distances to the edge (smaller than 50–100 nm), $\Phi_R(x)$ varies spatially, due to the excitation of deeply evanescent modes generated by the termination. These modes are reminiscent of the “quasicylindrical” waves originated by subwavelength emitters in both metals and graphene [29,30] and, in this problem, are responsible for a change in phase of the order of 15%. Second, at larger distances, $\Phi_R(x)$ converges to a GP reflection phase $\Phi_R \approx -0.75\pi$. Notably, this value is virtually independent of the intrinsic properties of graphene (Fermi level, temperature, etc.) and dielectric environment.

It is possible to obtain a good estimation of this nontrivial reflection phase, and further insight into its origin, by using a simple analytical model. Following an approach that was used to study the reflection of the surface plasmons in metal slabs [31], we neglect the complex behavior of the EM field close to the edge, and approximate the field at the graphene side by the sum of the incident and reflected GPs. The field is expanded in vacuum ($x > 0$) in its eigenstates, thus having the form

$$H_r(x,z) = \begin{cases} \pm (e^{ik_px} + r_{\ell} e^{-ik_px}) e^{ik_zz}, & x < 0, \\ \int_{-\infty}^{\infty} dk_z h(k_z) e^{ik_zz}, & x > 0, \end{cases}$$  \hspace{1cm} (2)

where $r_{\ell}$ and $h(k_z)$ are expansion coefficients, $\pm$ stand for $z > 0$ and $z < 0$, respectively (the magnetic field for a GP is antisymmetric with respect to the graphene position). The wave vector components are $k_{\ell p} = -g/\alpha$ (with $g = \omega/c$ and $\alpha = 2\pi\sigma/c$) and $k_p = \sqrt{g^2 - k_{\ell p}^2}$, $k_{\ell z} = k_{\ell z}(k_z) = \sqrt{g^2 - k_z^2}$, with $\text{Im}(k_{\ell p}), \text{Im}(k_{\ell z}) \geq 0$ to satisfy the radiation conditions. The electric field components can be found from Eqs. (2) using Maxwell’s equations. The unknown coefficients $r$ and $h(k_z)$ are obtained by imposing continuity of the magnetic fields and the $z$ component of the electric field along the plane $x = 0$ [32]. The final result for the reflection coefficient is

$$r_{\ell} = \frac{a - 1}{a + 1},$$  \hspace{1cm} (3)

where

$$a = \frac{4|k_{\ell p}| k_p}{\pi} \int_0^{\infty} dk_z \frac{k_z^2}{k_{\ell z}(k_{\ell z}^2 + k^2)^2}. $$  \hspace{1cm} (4)

This integral can be computed numerically [32], but an excellent analytical approximation can be found for the case with large values of $k_p$ (which is the case of interest, due to strong confinement of the GP). Noticing that the main contribution to the integral originates from $k_{\ell z} \sim |k_{\ell p}| > 1$, we can approximate $k_{\ell z} \approx ik_{\ell p}$, and obtain $a \approx -2i/\pi$, yielding a reflection phase $\Phi_R = \arctan[-4\pi/(4 + \pi^2)] \approx -0.64\pi$. Thus, this analytical result coincides with the phase extracted from full-wave calculations with 13% error, which is consistent with the neglected contributions from the highly confined modes in the graphene region that lead to the formation of the quasicylindrical wave close to the edge.

In order to get a better description of experimentally observed samples, let us extend the previous discussion to situations where the carrier density, and thus the conductivity $\sigma = \sigma(x)$, changes spatially close to the edge. In this case the reflection coefficient corresponds to the reflection from the whole inhomogeneous region, not only from the abrupt termination $x = 0$. However, taking into account that GPs can follow adiabatically variations in conductivity in length scales even smaller than the GP wavelength [25], we can hypothesize that the GP scattering can then be split into three “events”: (i) GP propagating through the inhomogeneity to the edge; (ii) reflection of the GP from the edge with the reflection coefficient $r_{\ell}$; and (iii) backward propagation of the reflected...
FIG. 3. (Color online) The phase of the reflection coefficient as a function of the distance from the edge (located at \( x = 0 \)) for two different profiles \( \sigma(x) = \sigma_0 F(x) \), with \( F(x) \) shown in the inset. Both \( \arg(r) \) (continuous curves) and \( \arg(r) - \Delta \phi \) (“corrected” phase, discontinuous curves) are rendered. The parameters used for graphene are the same as in Fig. 2.

GP \( r \) through the inhomogeneous region. In other words, the full reflection coefficient is simply the product of the reflection coefficient for the edge \( r_E \) and phase due to the propagation of the GP along the inhomogeneity region [32]:

\[
r = r_E e^{i \Delta \phi}, \quad \Delta \phi = 2i \int_{-\infty}^{0} dx [k_p(x) - k_{p0}],
\]

with \( k_{p0} = k_p(-\infty) \).

In order to check the validity of this approximation, we have carried out simulations for the two different conductivity profiles, rendered in the inset to Fig. 3(a). These profiles present a \( \sim 1/\sqrt{x} \) -like dependency for \( F(x) \) [32] since similar behavior of the Fermi level was found in electrostatically doped graphene ribbons [33]. Figure 3(a) shows that the argument of the reflection coefficient is very different for both profiles (rendered by the continuous curves). However, when corrected by the optical phase picked up by propagation in the nonuniform region, this argument converges to approximately \( -0.7\pi \). This phase is very close to the previously found value for the edge of a homogeneous sheet, thus confirming that, to a good approximation, the GP follows adiabatically the conductivity variation up to the edge.

GP modes in ribbons. Several experiments have analyzed the modes in arrays of graphene ribbons, illuminated at normal incidence with an electric field pointing perpendicularly to the ribbon axis, in terms of a Fabry-Perot model, where excited plasmons propagate back and forth between the ribbon edges. In a single homogeneous ribbon, with width \( W \), the modes should satisfy

\[
2k_p W + 2\Phi_R = 2\pi n,
\]

All analyses have, to the best of our knowledge, considered that the field vanishes at the edges, thus assuming \( \Phi_R = -\pi \).

In this case, the fundamental mode occurs for \( n = 0 \), leading to the commonly used expression \( k_p = \pi / W \). However, the existence of the nontrivial reflection phase analyzed in this Rapid Communication modifies this picture. For instance, notice that the fundamental mode occurring for \( n = 0 \) satisfies \( k_p = -\Phi_R / W \).

In order to illustrate this point, we have carried out simulations (using modal expansion [16]) of the transmission spectra \( T \) of normal-incidence electromagnetic waves, with the electric field polarized normal to the ribbons, impinging into arrays of ribbons placed on an insulating substrate. Resonances in the relative transmission, i.e., with respect to the graphene-free substrate case, correspond to enhanced absorption due to the excitation of graphene plasmons. In order to compare with experimental data [20], we have assumed an array period \( L = 2W \), a temperature of 300 K, a typical carrier relaxation time of 0.1 ps for chemical vapor deposited (CVD) graphene, and a SiO\(_2\) substrate whose dielectric function is taken from Ref. [20]. Figure 4(a) shows the intensity plot of the relative transmission computed for ribbon arrays with different widths. The white discontinuous lines provide the expected position of the resonances, based on Eq. (6), where \( k_p \) is given by the dispersion relation for graphene plasmons on a SiO\(_2\) substrate. The result of the mapping for the first three even modes

FIG. 4. (Color online) (a) Relative transmission \( \delta T = \left| 1 - T / T_0 \right| \) (with respect to the one for the graphene-free substrate) through the array of graphene ribbons on the SiO\(_2\) substrate as a function of the inverse ribbon width and wave number. The array has a period twice the ribbon’s width. (b) The same but for free-standing graphene. Circular symbols represent the experimental data. The discontinuous curves numbered by “0, 2, . . .” correspond to the modes given by Eq. (6). The discontinuous curve marked as “previous, \( n = 0 \)” corresponds to \( \Phi_R = -\pi \) and \( n = 0 \) in Eq. (6). The parameters used for graphene conductivity: temperature 300 K, Fermi level 0.55 eV, and the relaxation time of the charge carriers is 0.1 ps.
$n = 0, 2, 4$ is shown by the white discontinuous curves (modes characterized by odd integers are antisymmetric with respect to the ribbon axis and do not couple to normal-incidence radiation), in reasonably good agreement with the simulations. The open circles mark the spectral position for maximum experimental reflectance taken from Ref. [20]. By assuming a Fermi level of 0.55 eV, and an effective width of the ribbon 28 nm narrower than the nominal value, due to the presence of disorder close to the ribbon edge [20], we obtained very good agreement between experiment and theory. Remarkably, using the anomalous reflection phase computed for graphene plasmons provides a good approximation for the spectral position of different branches, not only the $n = 0$ one, for both measured and computed resonant spectra for ribbons. Notice that the deviation of the experimental points from the theoretically predicted positions of the resonances for large values of $1/W$ in Fig. 4(a) might be attributed to the growing influence of nonhomogeneously doped edges for very thin ribbons.

In Fig. 4(b) we render the computed results for a free-standing graphene sheet. In this plot we show the full calculation for a ribbon array, together with a prediction from the traditionally used expression $\Phi_0$ and that with the anomalous reflection phase using Eq. (6). Also in this case, the traditional model captures the trends but fails to reproduce accurately the spectral position for maximum transmission. In contrast, our simple Fabry-Perot model with nontrivial reflection phase $\Phi_R$ provides a good approximation to the computed resonant spectra for ribbons, especially for a small momentum (larger ribbon widths). Notice that, for the considered ratio between period and ribbon width, the ribbon-ribbon interaction affects mainly the lowest frequency resonance ($n = 0$) [16,23] and provides a slight redshift (around a few percent) of the resonance peak compared to the value predicted by Eq. (6). Calculations show that already for a slightly larger inter-ribbon distance ($L = 3W$) Eq. (6) provides a virtually exact value for the resonance spectra [32].

**Conclusions.** We have shown that when a plasmon in graphene is reflected from an abrupt termination, the phase of the reflected plasmon is largely independent on dielectric environment, wavelength, and local doping, provided that the GP is strongly confined. The reflection phase has a nontrivial value of $\Phi_R \approx -\frac{3\pi}{4}$. We reached our results using three different methods (finite element calculation, quasianalytical model, and a fully analytical approximation). Taking this phase into account is essential to design and analyze the optical properties of graphene resonators (ribbons, disks, etc.). By appropriately remapping the modes inside a single graphene ribbon, we have successfully fit the experimentally observed resonances in periodic arrays of graphene ribbons. Our results can be also further extended to other two-dimensional systems supporting plasmons (such as very thin metal films, topological insulators, transition polaritonic layers, etc.), where the phase of the reflection coefficient is normally, and perhaps incorrectly, assumed to be $-\pi$.

**Acknowledgments.** We express our sincere gratitude to F. Guinea for stimulating and fruitful discussions. We acknowledge support by the Spanish Ministerio de Economía y Competitividad within Project No. MAT2011-28581-C02. L.M.M. acknowledges support by the EC under Graphene Flagship (Contract No. CNECT-ICT-604391).


[27] A commercial software COMSOL has been used. Graphene has been simulated as a two-dimensional conductivity in the boundary conditions.


